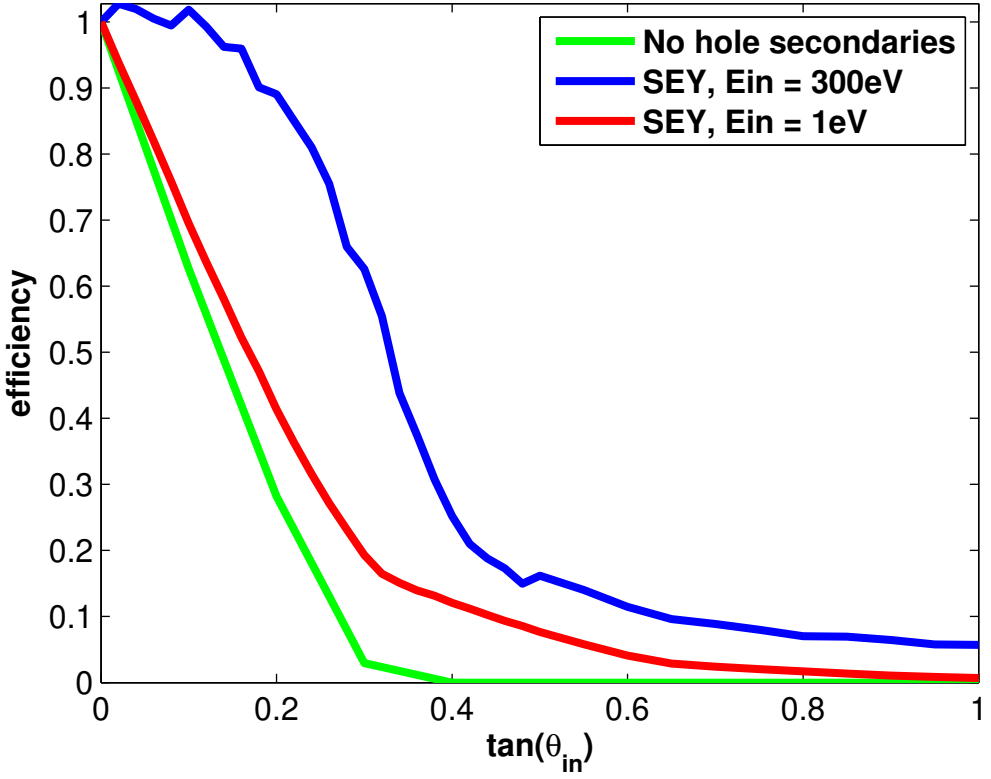
No hole secondaries
SEY, Ein = 300eV
SEY, Ein = 1eV
efficiency
tan(θin)
0
0.1
0.2
0.3
0.4
0.5
0.6
0.7
0.8
0.9
1
0
0.2
0.4
0.6
0.8
1